The ISL8560 is a step down DC/DC power switching regulator which accepts a 9 V to 60 V input, and provides up to 2 A of output current. The output voltage can be set between 1.21 V and 35 V by means of an external resistor divider. The device uses an internal power DMOS transistor with a typical $r_{\mathrm{DS}(\mathrm{ON})}$ of $0.19 \Omega$ to obtain very high efficiency and high switching speed. A switching frequency in the range of 100 kHz to 600 kHz can be realized (the maximum power dissipation of the various packages must be observed). Notable features of this next generation DC/DC converter include pulse-by-pulse current limit for FET protection, hiccup-mode short circuit protection, voltage feedforward, frequency SYNC, soft-start, low standby current of $60 \mu \mathrm{~A}$ typical in the disabled state and thermal shut-down. The device is available in a 20 Ld QFN package.

## Ordering Information

$\left.$| PART <br> NUMBER <br> (Note) | PART <br> MARKING | TEMP. <br> RANGE <br> ( |
| :--- | :--- | :---: | :---: | :---: |
| C) |  |  |$\quad$| PACKAGE |
| :---: |
| (Pb-free) |$\quad$| PKG. |
| :---: |
| DWG. \# | \right\rvert\,

*Please refer to TB347 for details on reel specifications.
NOTE: These Intersil Pb-free plastic packaged products employ special Pb-free material sets; molding compounds/die attach materials and 100\% matte tin plate PLUS ANNEAL - e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb -free soldering operations. Intersil Pb -free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb -free requirements of IPC/JEDEC J STD-020.

## Features

- Voltage feedforward
- Step down DC/DC supporting up to 2A
- Input voltage range of 9 V to 60 V
- Internal reference of $1.21 \mathrm{~V} \pm 1 \%$
- Adjustable output voltage range of 1.21 V to 35 V
- Adjustable switching frequency 100 kHz to 600 kHz
- Frequency SYNC pin
- Zero load current operation
- Pulse-by-pulse mode current limit
- Hiccup mode short-circuit protection
- Low standby current of $60 \mu \mathrm{~A}$ typical
- Thermal shut-down
- Transient survival up at 100 V for 400 ms
- Pb-free (RoHS compliant)


## Applications

- Industrial and automotive power supplies
- Portable computers
- Battery chargers
- Distributed power systems


## Related Literature

- Technical Brief TB363 "Guidelines for Handling and Processing Moisture Sensitive Surface Mount Devices (SMDs)"


## Pinouts



## What's Inside

The Evaluation Board Kit contains the following materials:

- The ISL8560EVAL2Z REVB board.
- The ISL8560 datasheet.
- ISL8560 Evaluation Board Application Note.


## Recommended Equipment

The following equipment is recommended to evaluate the performance of the board:

- 0 V to 100 V power supply with at least 5A current sourcing capability.
- Electronic Loads capable of sinking current up to 5A.
- Digital Multimeters (DMMs.)
- 100 MHz quad-trace Oscilloscope.
- Signal generator (to test the SYNC feature only).


## Quick Setup Guide

1. Ensure that the circuit is correctly connected to the supply and loads prior to applying any power.
2. Connect the bias supply to VIN, with the positive terminal connected to P1(VIN), and the return to P2(GND).
3. Connect the load across the output terminals, between pins P3 (positive) and P4 (return).
4. Verify that the jumper JP1 is connected.
5. Apply a voltage between 9 V and 60 V across the input.
6. Verify that the output voltage is 5 V .

## Evaluating the Other Output Voltage

The ISL8560EVAL2Z kit output is preset to 5 V . The output voltage can be adjusted from 1.21 V to 55 V by Equation 1 :
$\mathrm{R}_{1}=\left(\mathrm{R}_{2}\right) /\left(\left(\mathrm{V}_{\mathrm{OUT}} / \mathrm{V}_{\mathrm{FB} 1}\right)-1\right)$
with $\mathrm{R}_{2}=51.1 \mathrm{k} \Omega$ and $\mathrm{V}_{\mathrm{FB} 1}=1.21 \mathrm{~V}$.
Note: The inductor, output capacitors and the compensation network may need to be tweaked, along with the corresponding compensation network, for optimal performance with change in output voltage and/or load. Also, additional heatsinking or airflow may required to insure that the junction temperature does not exceed $+125^{\circ} \mathrm{C}$.

## Frequency

The ISL8560EVAL2Z kit is preset at 500 kHz . The ISL8560EVAL2Z can be adjusted to operate at switching frequencies from 100 kHz to 600 kHz . Use $\mathrm{C}_{16}$ to program the switching frequency using Equation 2 :
$\mathrm{C}_{16}[\mathrm{nF}]=\frac{6.25}{\mathrm{R}_{7}[\mathrm{k} \Omega]}\left(\frac{1000}{\mathrm{f}_{\mathrm{OSC}}[\mathrm{kHz}]}-0.3\right)$

## Synchronization

The ISL8560EVAL2Z circuit may be synchronized to a TTL signal that is set at a higher switching frequency than the pre-set frequency. The range of the external synchronizing frequency is from 100 kHz to 600 kHz . It is recommended to use and RTCT capacitor $\left(\mathrm{C}_{16}\right)$ of 2700 pF in this configuration.

TABLE 1. SWITCH 1 SETTINGS

| JP1 | ENABLE | OPERATING MODE |
| :---: | :--- | :--- |
| 1 | OPEN | Unit Disabled |
| 2 | GND | Unit Enabled |



TABLE 2. COMPONENT LIST

| REF DES | QTY | VALUE | TOL. | VOLTAGE | PACKAGE | PART NUMBER | MANUFACTURER | DESCRIPTION |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| C5, C10, C11 | 3 | $0.10 \mu \mathrm{~F}$ | 10\% | 50V | 0603 | C1608X7R1H104K-T | TDK | CAPACITOR, SMD, 0603, $0.10 \mu \mathrm{~F}, 50 \mathrm{~V}, 10 \%$, X7R |
| C12-C14 | 3 | $150 \mu \mathrm{~F}$ | 20\% | 25V | 8mmx10mm | EEE-FK1E151P-T | PANASONIC | CAPACITOR, SMD, 10.3 mm , $150 \mu \mathrm{~F}, 25 \mathrm{~V}, 20 \%$, ROHS, ALUM. ELEC. |
| C1-C3 | 3 | $47 \mu \mathrm{~F}$ | 20 | 100 V | $12.5 \mathrm{~mm} \times 13.5 \mathrm{~mm}$ | EEV-FK2A470Q-T | PANASONIC | CAPACITOR, SMD, H13, 47 $\mu$ F, 100V, 20\%, ROHS, ALUM. ELEC. |
| C7,C9 | 2 | 100pF | 5\% | 50V | 0603 | H1045-00101-50V5-T | AVX, Samsung, TDK, Murata, Vishay | CAPACITOR, SMD, 0603, 100pF, 50V, 5\%, NPO, ROHS |
| C15 | 1 | $0.01 \mu \mathrm{~F}$ | 10\% | 50V | 0603 | H1045-00103-50V10-T | AVX, Samsung, TDK, Murata, Vishay | CAPACITOR, SMD, 0603, $0.01 \mu \mathrm{~F}, 50 \mathrm{~V}, 10 \%, \mathrm{X7R}$, ROHS |
| C18 | 1 | $1 \mu \mathrm{~F}$ | 10\% | 16V | 0603 | H1045-00105-16V10-T | AVX, Samsung, TDK, Murata, Vishay | CAPACITOR, SMD, 0603, $1 \mu \mathrm{~F}$, 16V, 10\%, X7R, ROHS |
| C19 | 1 | 390pF | 5\% | 50V | 0603 | H1045-00391-50V5-T | AVX, Samsung, TDK, Murata, Vishay | CAPACITOR, SMD, 0603, 390pF, 50V, 5\%, NPO, ROHS |
| C8, C17 | 0 | OPEN | - | - | - | H1045-DNP | AVX, Samsung, TDK, Murata, Vishay | CAPACITOR, SMD, 0603, DNP-PLACE HOLDER, ROHS |
| C6 | 1 | $1.0 \mu \mathrm{~F}$ | 10\% | 25V | 0805 | H1046-00105-25V10-T | AVX, Samsung, TDK, Murata, Vishay | CAPACITOR, SMD, 0805, 1.0uF, 25V, 10\%, X7R, ROHS |
| C4 | 1 | $0.1 \mu \mathrm{~F}$ | 10\% | 100V | 1206 | H1065-00104-100V10-T | AVX, Samsung, TDK, Murata, Vishay | CAPACITOR, SMD, 1206, $0.1 \mu \mathrm{~F}, 100 \mathrm{~V}, 10 \%, \mathrm{X} 7 \mathrm{R}, \mathrm{ROHS}$ |
| C16 | 1 | 47pF | 5\% | 50V | 1206 | H1065-00471-100V5-T | AVX, Samsung, TDK, Murata, Vishay | CAPACITOR, SMD, 1206, 47pF, 50V, 5\%, NPO, ROHS |
| L1 | 1 | $22 \mu \mathrm{H}$ | 20\% | - | 18mmx15mm | DO5010H-223MLB | COILCRAFT | $\begin{aligned} & \text { COIL-PWR INDUCTOR, SMD, } \\ & 18 \times 15,22 \mu \mathrm{H}, 20 \%, 7 \mathrm{~A}, \text { ROHS, } \\ & 47 \mathrm{~m} \Omega \end{aligned}$ |
| JP1 | 1 | $0 \Omega$ | - | - | Header | SPC02SYAN | SULLINS | CONN-JUMPER, 2 PIN, SHUNT, ROHS |
| D1 | 1 | 5A |  | 100V | Power DI-5 | PDS5100H | DIODES INC. | DIODE-RECTIFIER, SMD, Power DI-5,100V, 5A, ROHS, SCHOTTKY |
| U1 | 1 | 2A | - | 72V | 6x6 QFN | ISL8560IRZ | INTERSIL | IC-STEP DOWN DC/DC CONVERTER, 20P, QFN, 6x6, ROHS |
| R9 | 1 | $20 \Omega$ | 1\% | 100V | 0603 | H2511-0200-1/10W1-T | PANASONIC | RESISTOR, SMD, 0603, 20, 1/10W, 1\%, TF, ROHS |
| R5, R6, R8 | 3 | 10k | 1\% | 100V | 0603 | H2511-1002-1/16W1-T | PANASONIC | RESISTOR, SMD, 0603, 10k, 1/16W, 1\%, TF, ROHS |
| R1 | 1 | 16.2k | 1\% | 100V | 0603 | H2511-1622-1/16W1-T | PANASONIC | RESISTOR, SMD, 0603, 16.2k, 1/16W, 1\%, TF, ROHS |
| R4 | 1 | 301k | 1\% | 100V | 0603 | H2511-3013-1/10W1-T | YAGEO | RESISTOR, SMD, 0603, 301k, 1/10W, 1\%, TF, ROHS |
| R2 | 1 | 51.1k | 1\% | 100 V | 0603 | H2511-05112-1/16W1-T | PANASONIC | RESISTOR, SMD, 0603, 51.1k, 1/16W, 1\%, TF, ROHS |
| R3 | 1 | 5.62k | 1\% | 100V | 0603 | H2511-5621-1/16W1-T | PANASONIC | RESISTOR, SMD, 0603, 5.62k, 1/16W, 1\%, TF, ROHS |
| R7 | 1 | 20k | 1\% | 100V | 0603 | H2513-02002-1/4W1-T | PANASONIC | RESISTOR, SMD, 1206, 20k, 1/4W, 1\%, TF, ROHS |
| R10 | 1 | $0 \Omega$ | 1\% | 100 V | 0603 | H2515-00R00-1W-T | VENKEL | RESISTOR, SMD, 2512, 0 2 , 1W, TF, ROHS |

## ISL8560EVAL2Z Board Layout



FIGURE 1. TOP COMPONENTS


FIGURE 2. TOP LAYER ETCH

ISL8560EVAL2Z Board Layout (Continued)


FIGURE 3. 2ND LAYER ETCH


FIGURE 4. 3RD LAYER ETCH

ISL8560EVAL2Z Board Layout (Continued)


FIGURE 5. BOTTOM LAYER COMPONENTS (MIRRORED)


FIGURE 6. BOTTOM LAYER ETCH (MIRRORED)

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